

• Product Summary

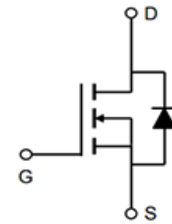
Part #	V_{DS}	$R_{DS(on).typ}$ (@ $V_{GS}=10V$)	$R_{DS(on).typ}$ (@ $V_{GS}=4.5V$)	I_D
EFM5N10	100V	115m Ω	130m Ω	5A

• Features

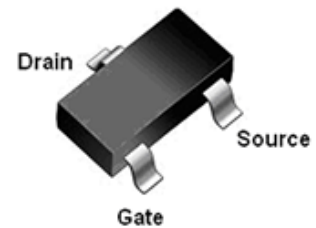
- Low $R_{DS(on)}$ @ $V_{GS}=10V$
- 4.5V Logic Level Control
- N Channel SOT23 Package
- Pb-Free, RoHS Compliant

• Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply
- Motor control



N-Channel MOSFET



SOT-23L



• Ordering Information:

Part NO.	EFM5N10
Marking	5N10
Packing Information	REEL TAPE
Basic ordering unit (pcs)	3000

• Absolute Maximum Ratings ($T_C=25^{\circ}C$)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	5	A
Drain Current-Pulsed ^(Note 1)	I_{DM}	21	A
Maximum Power Dissipation	P_D	5	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^{\circ}C$

• Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	$R_{\theta JA}$	41.7	$^{\circ}C/W$
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• Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

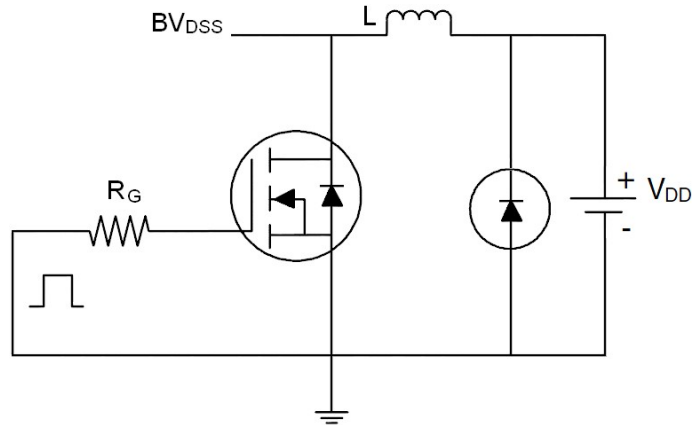
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250uA	100	--	--	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V V _{GS} =0V	--	--	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V V _{DS} =0V	--	--	±100	nA
On Characteristics ^(Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} I _D =250uA	1.0	1.8	3.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V I _D =5A	--	115	125	mΩ
		V _{GS} =4.5V I _D =4A	--	130	145	mΩ
Dynamic Characteristics ^(Note4)						
Input Capacitance	C _{Iss}	V _{DS} =50V V _{GS} =0V F=1.0MHz	--	210	--	PF
Output Capacitance	C _{Oss}		--	30	--	PF
Reverse Transfer Capacitance	C _{rss}		--	14	--	PF
Forward Transconductance	g _{FS}	V _{DS} =5V,I _D =2.9A	--	8	--	S
Switching Characteristics ^(Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =50V I _D =5A V _{GS} =10V R _G =2.5Ω,	--	15	--	nS
Turn-on Rise Time	t _r		--	3.4	--	nS
Turn-Off Delay Time	t _{d(off)}		--	21	--	nS
Turn-Off Fall Time	t _f		--	3.1	--	nS
Total Gate Charge	Q _g	V _{DS} =50V I _D =5A V _{GS} =10V	--	4.5	--	nC
Gate-Source Charge	Q _{gs}		--	1.5	--	nC
Gate-Drain Charge	Q _{gd}		--	1.2	--	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage ^(Note 3)	V _{SD}	V _{GS} =0V I _S =5A	--	0.79	1.2	V
Diode Forward Current ^(Note 2)	I _S		--	--	5	A

Notes:

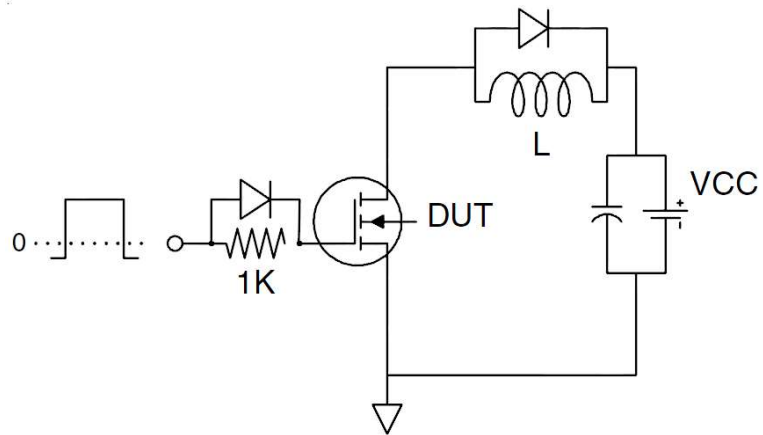
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production

• **Test Circuit**

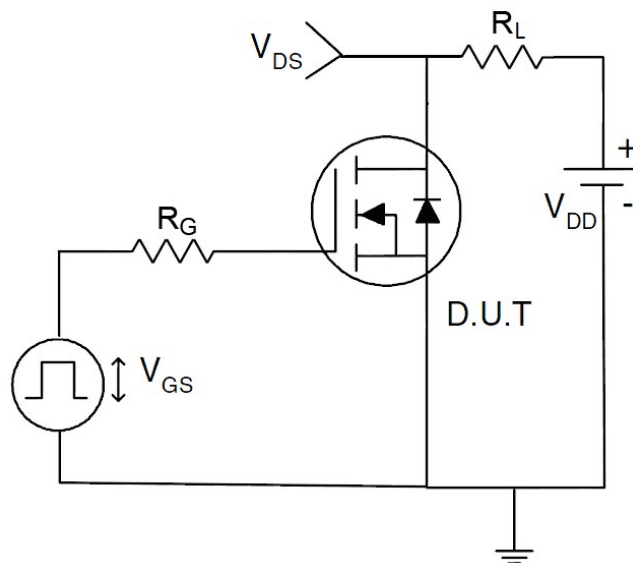
1) **E_{AS} test circuit**



2) **Gate charge test circuit**



3) **Switch Time Test Circuit**



• Typical Characteristics

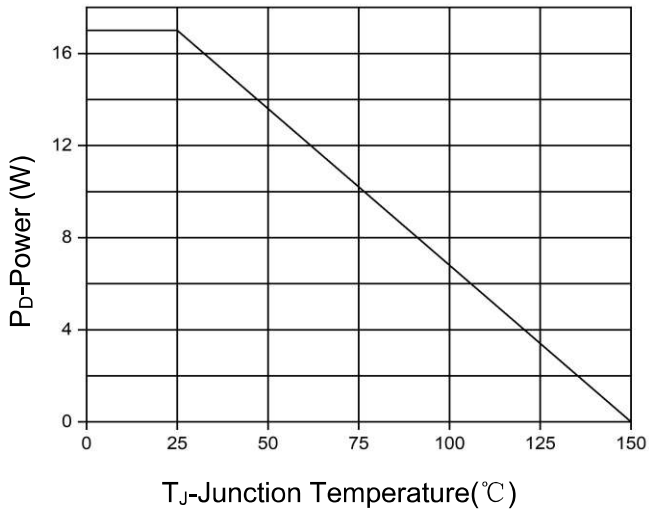


Figure 1. Power Dissipation

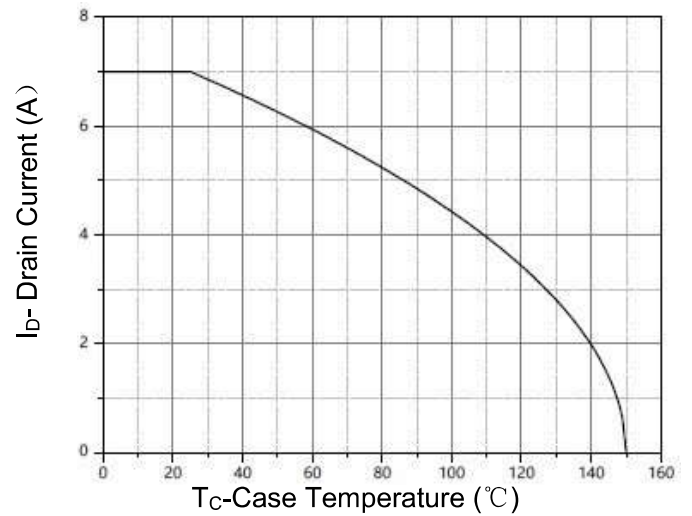


Figure 2. Drain Current

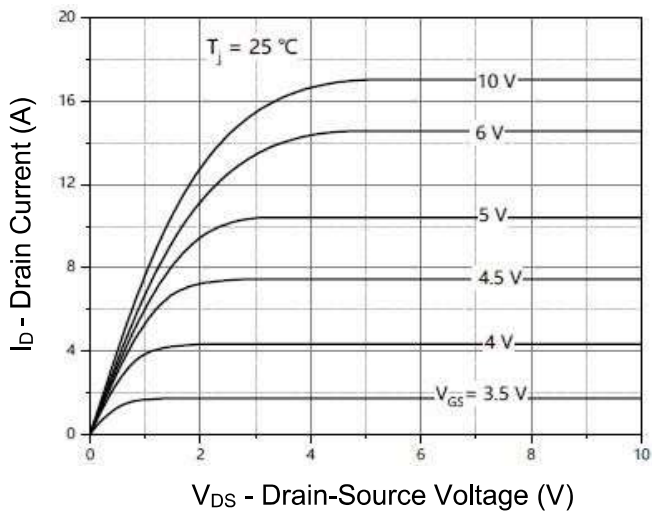


Figure 3. Output characteristics

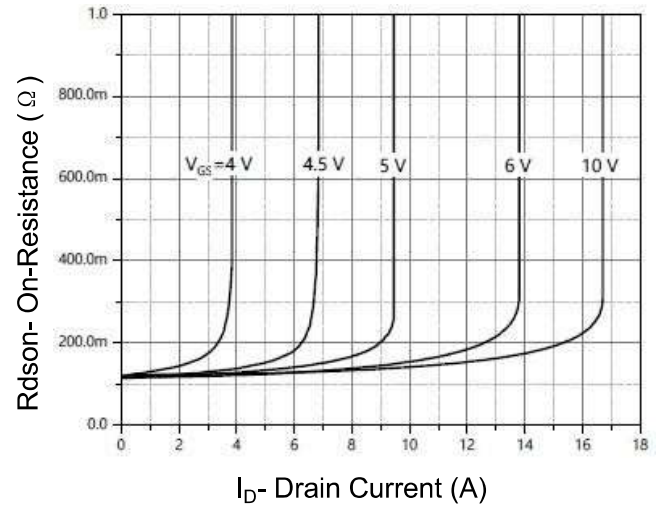


Figure 4. Drain-Source On-state resistance

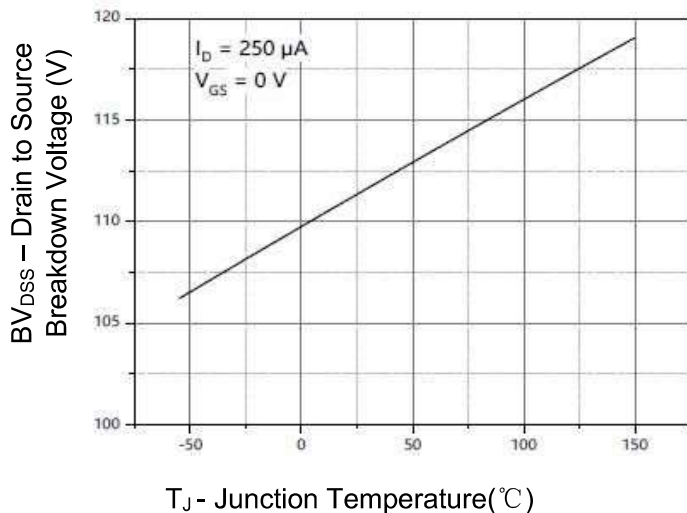


Figure 5. Drain-source breakdown voltage

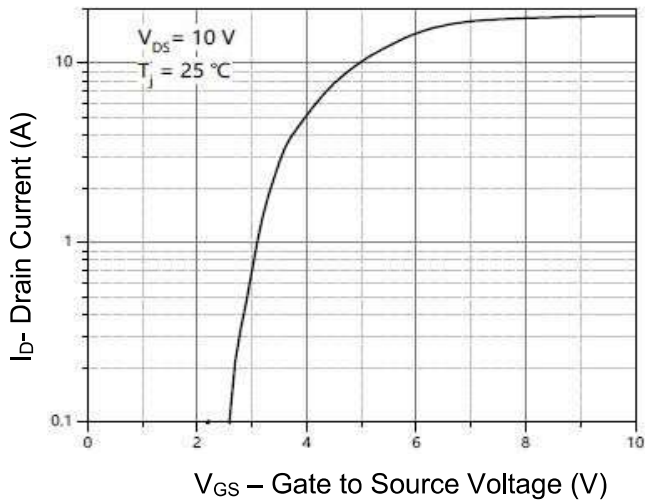


Figure 6. Transfer Characteristics

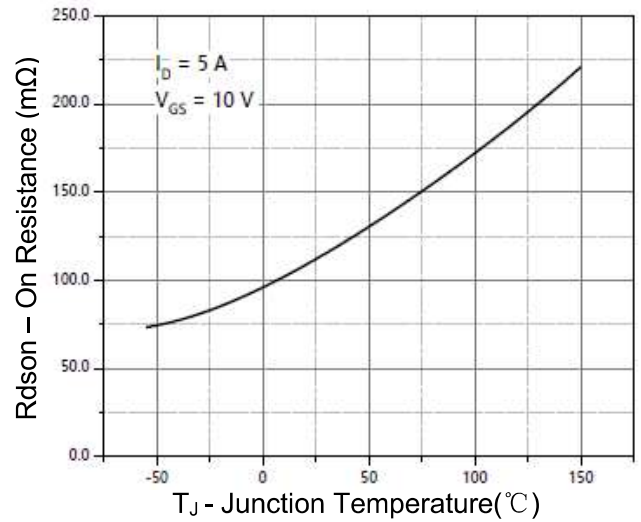


Figure 7. Drain-Source On-State Resistance

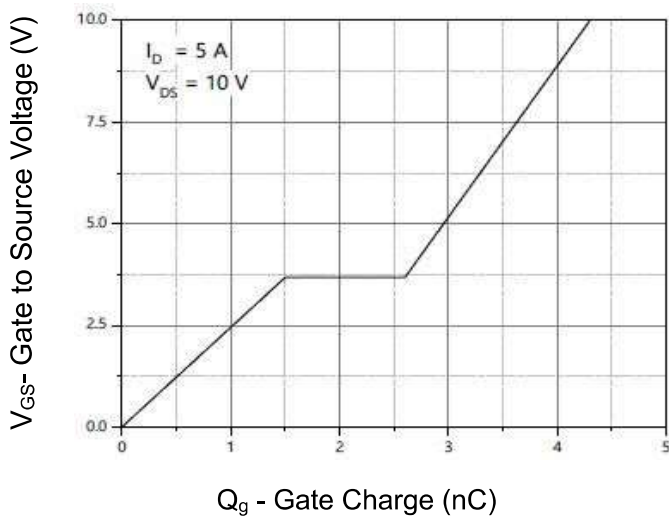


Figure 8. Gate Charge

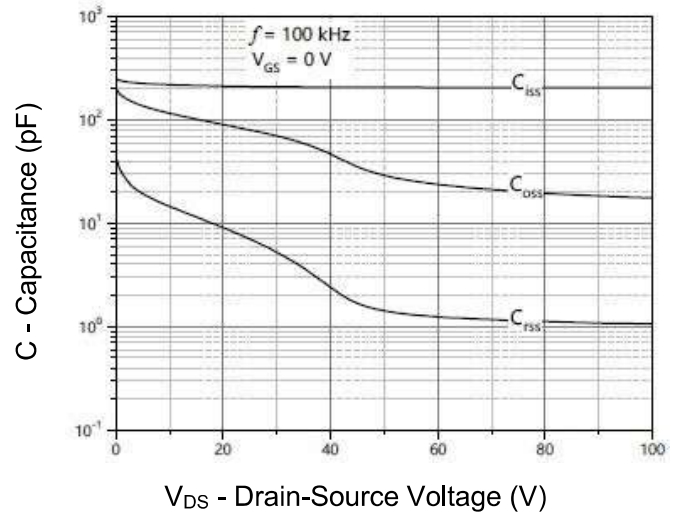


Figure 9 . Capacitance vs Vds

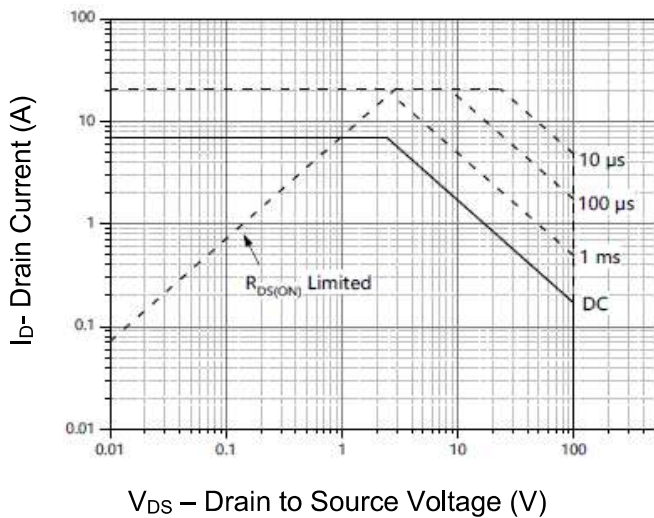


Figure 10. Safe Operation Area

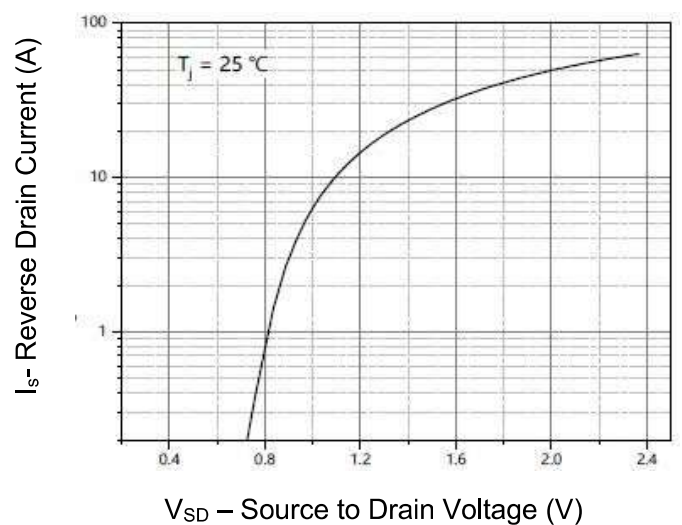
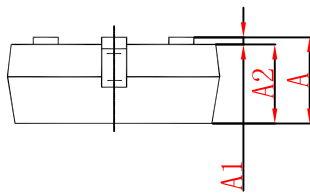
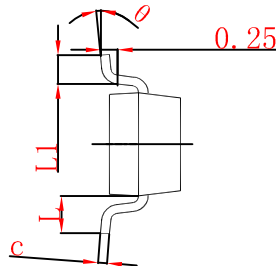
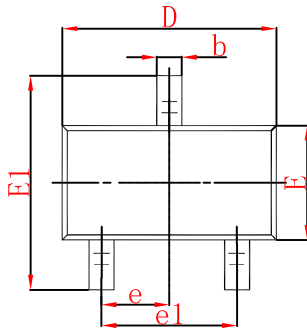
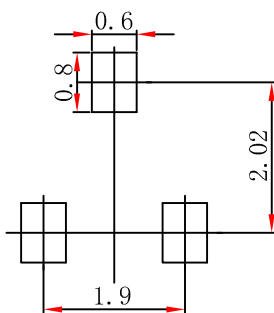


Figure 11. Source- Drain Diode Forward

SOT-23L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.